

View Online at <https://aerobasegroup.com/nsn/5961-01-034-4950>

Inclosure Material:

Metal

Overall Length:

1.330 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

Component Function Relationship:

Matched

Component Name And Quantity:

4 transistor

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

275.0 collector to base voltage/static/emitter open and 250.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

30.00 amperes source cutoff current

Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector preset

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Matched set of 4 transistors; matched to within 200 mv maximum vce; matched to within 20% of the mean beta for that group of 4

Test Data Document:

34217-6020028 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0